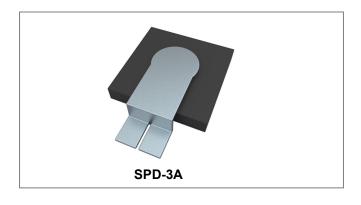




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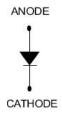
## Power Surface Mount Schottky Rectifier (20V, 120Amp)



#### Features

- 150°C T<sub>J</sub> operation
- Low forward voltage drop
- Low reverse leakage current
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Schematic & Pin Configuration**



#### **Applications**

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	20	V
Average Rectified Forward Current	IF (AV)	50% duty cycle @T $_{c}$ =116°C, rectangular wave form	120	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1650	А

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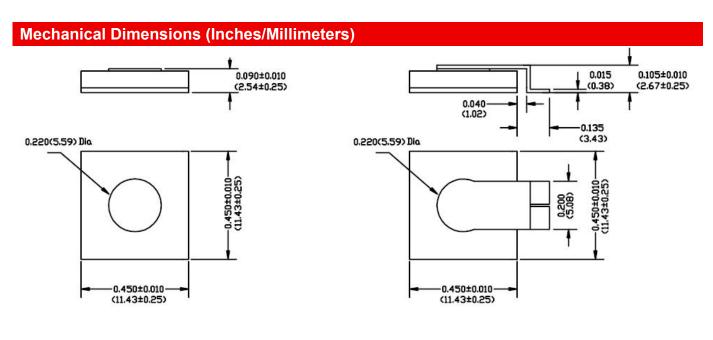
#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.42	0.48	V
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.29	0.35	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R, Pulse, T_J = 25 °C$	2	12	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , Pulse, T <sub>J</sub> = 125 °C	1000	1320	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	6500	8100	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

#### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	0.20	°C/W



SPD-3



### Suffix "R" Denotes Reversed Polarity

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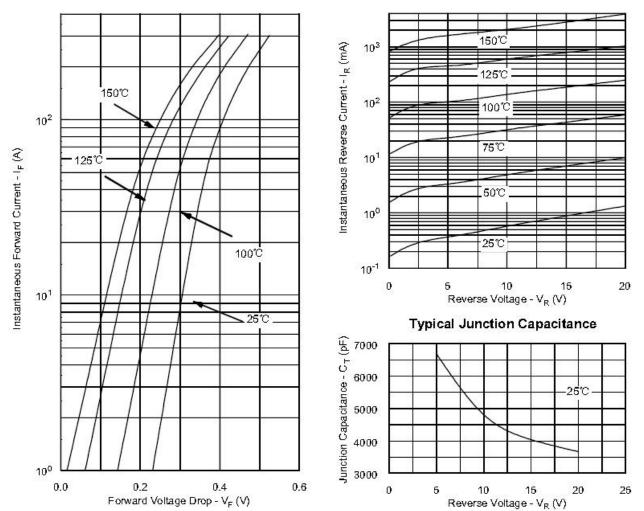


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### **Ratings and Characteristics Curves**



#### **Typical Forward Characteristics**

#### **Typical Reverse Characteristics**

### **Ordering Information**

Device	Package	Shipping	
127SPC020(A)	SPD-3A(Pb-Free)	100pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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